NSN 5961-01-251-5679

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-251-5679 **Inclosure Material:** Plastic **Overall Length:** 0.210 inches **Terminal Length:** 0.500 inches **Overall Height:** 0.165 inches **Overall Width:** 0.205 inches **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-92 **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 40.0 collector to base voltage/static/emitter open and 12.0 collector to emitter voltage/static/base open and 4.5 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 200.00 milliamperes source cutoff current **Transfer Ratio:** 40.0 static forward current transfer ratio, common-emitter and 120.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 165.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No